

STPS61170C

High voltage power Schottky rectifier

Features

- High junction temperature capability
- Low leakage current
- Good trade off between leakage current and forward voltage drop
- Low thermal resistance
- High frequency operation
- Avalanche specification

Description

Dual center tab Schottky rectifier suited for high frequency switched mode power supply.

Packaged in TO-247, this device is intended for use to enhance the reliability of the application.

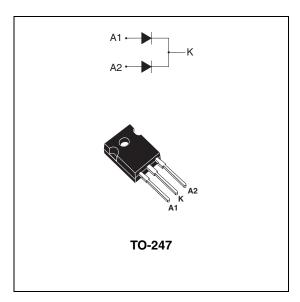


Table 1. Device summary

Symbol	Value
I _{F(AV)}	2 x 30 A
V_{RRM}	170 V
T _j	175 °C
V _{F (max)}	0.67 V

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1 **Characteristics**

Table 2. Absolute ratings (limiting values, per diode)

Symbol	Parameter			Value	Unit	
V_{RRM}	Repetitive peak reverse voltage			170	V	
I _{F(RMS)}	Forward rms current				80	Α
1	Per diode		30	Α		
l _{F(AV)}	Average forward current	$T_{C} = 150 ^{\circ}\text{C} \delta = 0.5$		Per device	60	
I _{FSM}	Surge non repetitive forward current $t_p = 10 \text{ ms sinusoidal}$			500	Α	
P _{ARM}	Repetitive peak avalanche power $t_p = 1 \mu s T_j = 25 °C$				31800	W
V _{ARM} ⁽¹⁾	Maximum repetitive peak avalanche voltage $t_p = 1 \mu s, T_j < 150 ^{\circ}C,$			200	٧	
V _{ASM} ⁽¹⁾	Maximum single pulse peak avalanche voltage			200	v	
T _{stg}	Storage temperature range			-65 to + 175	°C	
Tj	Maximum operating junction temperature ⁽²⁾			175	°C	
dV/dt	Critical rate of rise reverse voltage			10000	V/µs	

Table 3. Thermal resistance parameters

Symbol	Parameter		Value	Unit
R _{th (j-c)}	Junction to case	er diode otal	0.9 0.6	°C/W
R _{th (c)}	Coupling		0.3	

When the diodes 1 and 2 are used simultaneously:

 ΔT_i (diode 1) = P(diode1) x $R_{th(i-c)}$ (Per diode) + P(diode 2) x $R_{th(c)}$

Table 4. Static electrical characteristics (per diode)

Symbol	Parameter	Tests conditions		Min.	Тур.	Max.	Unit
. (1)	I _R ⁽¹⁾ Reverse leakage current	T _j = 25 °C	$V_R = V_{RRM}$			60	μΑ
'R`		T _j = 125 °C			16	60	mA
V _F ⁽²⁾ Forward voltage drop		T _j = 25 °C	I _F = 30 A			0.84	
	T _j = 125 °C	IF = 30 A		0.63	0.67	V	
	i oiwaiu voilage diop	T _j = 25 °C	I _F = 60 A			0.92	•
		T _j = 125 °C			0.76	0.80	

^{1.} Pulse test: $t_p = 5$ ms, $\delta < 2\%$

To evaluate the conduction losses use the following equation : P = 0.54 x $I_{F(AV)}$ + 0.0043 $I_{F}^{\,2}_{(RMS)}$

$$P = 0.54 \text{ x } I_{F(AV)} + 0.0043 I_{F^2(BMS)}$$

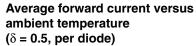
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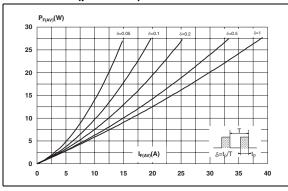
 $[\]frac{dPtot}{dTj} < \frac{1}{Rth(j-a)}$ condition to avoid thermal runaway for a diode on its own heatsink

^{2.} Pulse test: $t_p = 380 \mu s$, $\delta < 2\%$

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Figure 1. Average forward power dissipation Figure 2. versus average forward current (per diode)





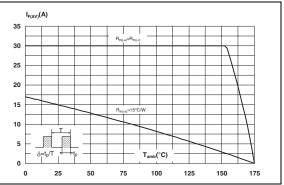
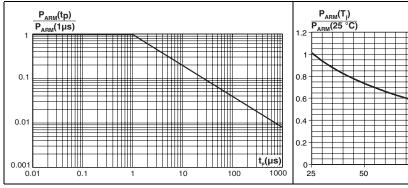


Figure 3. Normalized avalanche power derating versus pulse duration

Figure 4. Normalized avalanche power derating versus junction temperature



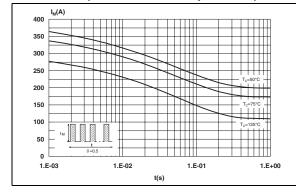
PARM(1)
PARM(25 °C)

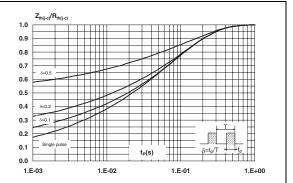
1.2
PARM(25 °C)

1.

Figure 5. Non repetitive surge peak forward current versus overload duration (maximum values, per diode)

Figure 6. Relative variation of thermal impedance junction to case versus pulse duration (per diode)

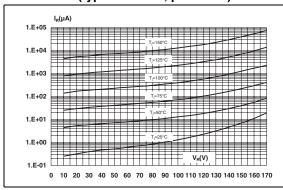




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Figure 7. Reverse leakage current versus reverse voltage applied (typical values, per diode)

Figure 8. Junction capacitance versus reverse voltage applied (typical values, per diode)



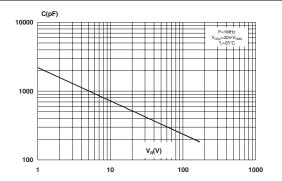
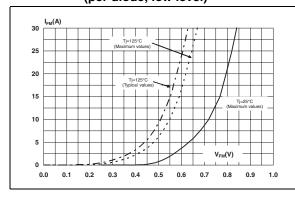


Figure 9. Forward voltage drop versus forward current (per diode, low level)

Figure 10. Forward voltage drop versus forward current (per diode, high level)



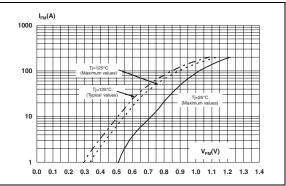
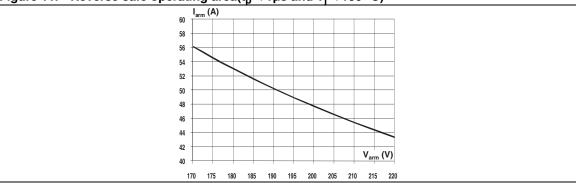


Figure 11. Reverse safe operating area($t_p < 1\mu s$ and $T_i < 150$ °C)



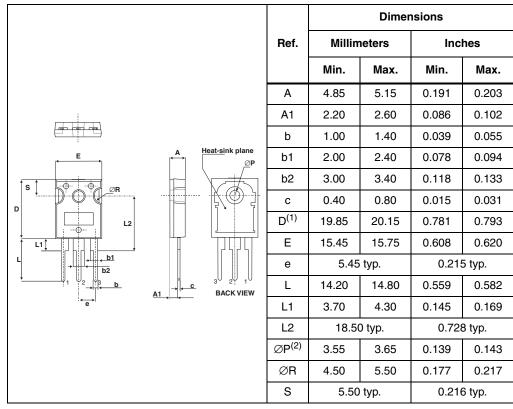
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2 Package information

- Epoxy meets UL94,V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.55 to 1.0 N⋅m

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Table 5. TO-247 dimensions



- 1. Dimension D plus gate protrusion does not exceed 20.5 mm
- 2. Resin thickness around the mounting hole is not less than 0.9 mm

Ordering information STPS61170C

3 Ordering information

Table 6. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS61170CW	STPS61170CW	TO-247	4.40 g	30	Tube

4 Revision history

Table 7. Document revision history

Date	Revision	Changes	
16-Sep-2005	1	First issue.	
01-Dic-2010	2	Updated Table 2 and added Figure 11.	

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